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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/608,081	06/30/2003	Kye Nam Lee	40296-0024	7874
26633	7590 12/22/2005		EXAM	INER
HELLER EHRMAN WHITE & MCAULIFFE LLP			VINH, LAN	
	ISLAND AVE, NW DN, DC 20036-3001		ART UNIT	PAPER NUMBER
	,		1765	
			DATE MAILED: 12/22/200	5

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/608,081	LEE ET AL.	
Office Action Summary	Examiner	Art Unit	
	Lan Vinh	1765	
The MAILING DATE of this communicatio Period for Reply	n appears on the cover sheet	with the correspondence address -	
A SHORTENED STATUTORY PERIOD FOR R THE MAILING DATE OF THIS COMMUNICATI - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communicati - If the period for reply specified above is less than thirty (30) days - If NO period for reply is specified above, the maximum statutory i - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON. FR 1.136(a). In no event, however, may on. , a reply within the statutory minimum of the period will apply and will expire SIX (6) Minimum, statute, cause the application to become	a reply be timely filed nirty (30) days will be considered timely. DNTHS from the mailing date of this communication. ABANDONED (35 U.S.C. § 133).	
Status			
1)⊠ Responsive to communication(s) filed on 2a)□ This action is FINAL.	This action is non-final.	• •	
Disposition of Claims			
4) ☐ Claim(s) 1-3 is/are pending in the applica 4a) Of the above claim(s) is/are wit 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-3 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction at a subject to Papers 9) ☐ The specification is objected to by the Example 1.	hdrawn from consideration. and/or election requirement.		
· ·	i⊓mer.] accepted or b)[_] objected t	n by the Examiner	
Applicant may not request that any objection t	, , , , , , , , , , , , , , , , , , , ,		
Replacement drawing sheet(s) including the country of the oath or declaration is objected to by the country of the oath or declaration is objected to by the oath or declaration is objected to be objected	•	-,, ,	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for fo a) All b) Some * c) None of: 1. Certified copies of the priority docu 2. Certified copies of the priority docu 3. Copies of the certified copies of the application from the International B * See the attached detailed Office action for	ments have been received. ments have been received in e priority documents have bee ureau (PCT Rule 17.2(a)).	Application No. <u>10/608,081</u> . en received in this National Stage	
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-94 3) Information Disclosure Statement(s) (PTO-1449 or PTO/S	8) Paper N	v Summary (PTO-413) o(s)/Mail Date f Informal Patent Application (PTO-152) 	

U.S. Patent and Trademark Office PTOL-326 (Rev. 1-04) Art Unit: 1765

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 11/28/2005 has been entered.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1, 3 are rejected under 35 U.S.C. 102(e) as being anticipated by Schwarz (US 6,972,265)

Schwarz discloses a method for fabricating an MTJ stack/ cell comprising the steps of:

forming a metal layer 26 connected to a semiconductor substrate 22 through a lower dielectric/ insulating layer (col 7, lines 30-32)

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sequentially forming a pinned magnetic layer 28, a tunnel barrier layer 32 and free magnetic layer 34 on the metal layer 26 (col 8, lines 30-32; col 9, lines 46-48) forming a metal layer 36/hard mask layer on the magnetic layer 34 (col 10, lines 44-48; fig. 4)

the hard mask layer 36 and the free magnetic layer 34 are patterned using an etching step and MTJ cell mask 38 as seen in fig. 4, the tunnel barrier layer 32 is exposed after the patterning step (col 11, lines 10-15)

sequentially forming a barrier layer 42 and insulating layer 50 of silicon oxide claim 3 on the entire surface (col 12, lines 50-55, col 15, lines 4-6)

anisotropically etching the insulating film to form an insulating spacer on a sidewall of the layer 36/hard mask, magnetic layer 34 and barrier layer 32 (col 15, lines 5-20; fig. 8) etching the tunnel layer 32, the pinned magnetic layer 28 and metal layer 42 using the insulating spacer and the hard mask layer as a mask to define/form MTJ cell and a connection layer (col 13, lines 1-22, fig. 6a)

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over Schwarz (US 6,972,265) in view of Parkin et al (US 6,518,588)

Schwarz's method has been described above. Unlike the instant claimed invention as per claim 2, Schwarz fails to disclose forming a Ta barrier layer and an insulating oxide film

Parkin discloses a method for forming a MRAM comprises the steps forming a TaN barrier layer and a insulating oxide film (col 3, lines 34-35, col 6, lines 9-10)

Since both Schwarz and Parkin are directed to method of forming magnetic semiconductor device, one skilled in the art at the time the invention was made would have found it obvious to modify Schwarz by forming a barrier layer of Ta in view of Parkins teaching because Parkin discloses that TaN which acts as a thermal diffusion barrier are also useful for magnetic tunnel junction device (col 6, lines 66-67)

Response to Arguments

6. Applicant's arguments with respect to claims 1-3 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lan Vinh whose telephone number is 571 272 1471. The examiner can normally be reached on M-F 8:30-5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571 272 1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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December 15, 2005